

**SHILING** Power Module, **MDST150A** is complex isolated module which is designed for rash current circuit.

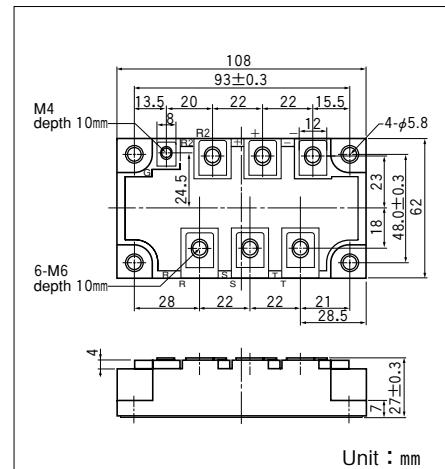
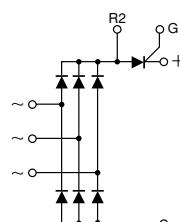
It contains six diodes connected in a three phase bridge configuration, and a thyristor connected to a direct current line.

- This Module is designed very compactly. Because diode module and thyristor put together.

- This Module is also isolated type between electorode terminal and mounting base. So you can put this Module and other one together in a same fin.

#### (Application)

- Inverter for AC or DC motor control, Current stabilized power supply, Switching power supply.



#### ● DIODE

#### ■ Maximum Ratings

( $T_j=25^\circ\text{C}$  unless otherwise specified)

Symbol	Item	Ratings		Unit
		MDST150A800V	MDST150A1600V	
$V_{RRM}$	Repetitive Peak Reverse Voltage	800	1600	V
$V_{RSM}$	Non-Repetitive Peak Reverse Voltage	960	1700	V

Symbol	Item	Conditions	Ratings	Unit
$I_D$	Output Current (D.C.)	Three phase full wave, $T_c=93^\circ\text{C}$	150	A
$I_{FSM}$	Surge forward current	1 cycle, 50/60Hz, peak value, non-repetitive	1460/1600	A
$T_j$	Operating Junction Temperature		-40 to +150	°C
$T_{stg}$	Storage Temperature		-40 to +125	°C
$V_{iso}$	Isolation Breakdown Voltage (R.M.S.)	A.C. 1minute	2500	V
	Mounting Torque	Mounting (M5)	Recommended Value 1.5-2.5 (15-25)	N·m (kgf·cm)
		Terminal (M6)	Recommended Value 2.5-3.9 (25-40)	
		Terminal (M4)	Recommended Value 1.0-1.4 (10-14)	
	Mass	Typical Value	460	g

#### ■ Electrical Characteristics

Symbol	Item	Conditions	Ratings	Unit
$I_{RRM}$	Repetitive Peak Reverse Current,max.	$T_j=150^\circ\text{C}$ , $V_R=V_{RRM}$	15	mA
$V_{FM}$	Forward Voltage Drop,max.	$I_F=150\text{A}$ , Inst. measurement	1.35	V
$R_{th(j-c)}$	Thermal Impedance, max.	Junction to Case (TOTAL)	0.14	°C/W
$R_{th(c-f)}$	Thermal Impedance, max.	Case to fin	0.07	°C/W

## ■ Maximum Ratings

(T<sub>j</sub>=25°C unless otherwise specified)

Symbol	Item	Ratings		Unit
		MDST150A800V	MDST150A1600V	
V <sub>RRM</sub>	Repetitive Peak Reverse Voltage	800	1600	V
V <sub>RSM</sub>	Non-Repetitive Peak Reverse Voltage	960	1700	V
V <sub>DRM</sub>	Repetitive Peak off-State Voltage	800	1600	V

Symbol	Item	Conditions	Ratings	Unit
I <sub>T(AV)</sub>	Average On-State Current	Singl phase half wave. 180° conduction, T <sub>c</sub> =93°C	150	A
I <sub>TSM</sub>	Surge On-State Current	1 cycle, 50/60Hz, peak value, non-repetitive	1460/1600	A
I <sup>2</sup> t	I <sup>2</sup> t (for fusing)		10670	A <sup>2</sup> s
di/dt	Critical Rate of Rise of On-State Current	I <sub>G</sub> =100mA, V <sub>D</sub> =½V <sub>DRM</sub> , di <sub>G</sub> /dt=0.1A/μs	150	A/μs
V <sub>iso</sub>	Isolation Breakdown Voltage (R.M.S.)	A.C. 1minute	2500	V
T <sub>j</sub>	Operating Junction Temperature		-40 to +135	°C
T <sub>stg</sub>	Storage Temperature		-40 to +125	°C
Mounting Torque	Mounting (M5)	Recommended Value 1.5-2.5 (15-25)	2.7 (28)	N·m (kgf·cm)
	Terminal (M6)	Recommended Value 2.5-3.9 (25-40)	4.7 (48)	
	Terminal (M4)	Recommended Value 1.0-1.4 (10-14)	1.5 (15)	
Mass	Typical Value		460	g

## ■ Electrical Characteristics

Symbol	Item	Conditions	Ratings	Unit
I <sub>DRM</sub>	Repetitive Peak Off-State Current,max.	T <sub>j</sub> =135°C, V <sub>D</sub> =V <sub>DRM</sub>	100	mA
I <sub>RRM</sub>	Repetitive Peak Reverse Current,max.	T <sub>j</sub> =135°C, V <sub>D</sub> =V <sub>RRM</sub>	100	mA
V <sub>TM</sub>	Peak On-State Voltage,max.	T <sub>j</sub> =25°C, I <sub>T</sub> =150A,, Inst. measurement	1.35	V
I <sub>GT</sub>	Gate Trigger Current,max.	T <sub>j</sub> =25°C, V <sub>D</sub> =6V, I <sub>T</sub> =1A	70	mA
V <sub>GT</sub>	Gate Trigger Voltage,max.	T <sub>j</sub> =25°C, V <sub>D</sub> =6V, I <sub>T</sub> =1A	3	V
dv/dt	Critical Rate of Rise of Off-State Voltage,min.	T <sub>j</sub> =125°C, V <sub>D</sub> =⅔V <sub>DRM</sub>	500	V/μs
R <sub>th(j-c)</sub>	Thermal Impedance, max.	Junction to Case	0.21	°C/W
R <sub>th(c-f)</sub>	Thermal Impedance, max.	Case to fin	0.07	°C/W

